G192121

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# APJ ABDUL KALAM TECHNOLOGICAL UNIVERSITY

SEVENTH SEMESTER B.TECH DEGREE EXAMINATION(R&S), DECEMBER 2019

### **Course Code: EC469**

### **Course Name: OPTO ELECTRONIC DEVICES**

Max. Marks: 100

### Duration: 3 Hours

(5)

### PART A

## Answer any two full questions, each carries 15 marks. Marks

- 1 a) Derive an equation for radiative lifetime for spontaneous band to band (5) recombination.
  - b) With the help of suitable diagram discuss band to band absorption and (10) recombination process in semiconductor.
- 2 a) Explain the need for laser cavity.
  - b) With the aid of suitable diagram discuss heterojunction laser. Mention two (10) disadvantage of homogeneous laser.
- 3 a) Discuss the principle of exciton absorption and free carrier absorption (7)
  - b) Find out total number of longitudinal modes and frequency spacing between the (8) modes of an AlGaAs laser supported by the gain spectrum which has a bandwidth of 6 nm. The laser has a cavity length of 200  $\mu$ m and the emission wavelength is 800 nm. (Assume n<sub>r</sub> = 3.6)

### PART B

### Answer any two full questions, each carries 15 marks.

- 4 a) Explain the generation of white light using dichromatic light emitting diode (5)
  - b) Draw the structure of InGaN/GaN light emitting diodes and discuss the (10) properties of such light emitting diodes
- 5 a) Differentiate between Kerr and Pockel effects (5)
  - b) What is meant by electro-optic effect? Explain the working principle of electro- (10) optic phase modulator.
- 6 a) Explain the generation of white light using wavelength convertors (7)

(10)

b) Explain the working principle of electro-absorption with any one type of (8) modulator.

### PART C

### Answer any two full questions, each carries 20 marks.

- 7 a) Explain different types of fixed optical filters
  - b) Describe the structure of Polymer LED. List the advantages and disadvantages of (10) Polymer LED.
- 8 a) With suitable diagram explain unidirectional and bidirectional WDM (10) transmission system.
  - b) A Si APD has a QE of 70 % at 830 nm in the absence of multiplication, that is (10)
    M = 1. The APD is biased to operate with a multiplication of 100. If the incident optical power is 10 nW, what is the photocurrent?
- 9 a) Explain different types of add and drop multiplexer. (10)
  - b) Describe the structure of thin film transistor display. (10)

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